M ethod for direct observation of coherent quantum oscillations in a superconducting phase qubit

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T in e-dom ain observations of coherent oscillations between quantum states in m esoscopic superconducting systems were so far restricted to restoring the time-dependent probability distribution from the readout statistics. We propose a new m ethod for direct observation of R abioscillations in a phase qubit. The external source, typically in G H z range, induces transitions between the qubit levels. The resulting R abioscillations of supercurrent in the qubit loop induce the voltage oscillations across the coil of a high quality resonant tank circuit, inductively coupled to the phase qubit. It is the presence of these voltage oscillations in the detected signal which reveals the existence of R abi oscillations in the qubit. D etailed calculation for zero and non-zero tem perature are m ade for the case of persistent current qubit. A ccording to the estim ates for decoherence and relaxation tim es, the e ect can be detected using conventional rf circuitry, with R abi frequency in M H z range.

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I. IN TRODUCTION

As is known the persistent current qubit (phase qubit) is one of the candidates as a key element of a scalable solid state quantum processor.^{1,2} The basic dynamic manifestations of a quantum nature of the qubit are macroscopic quantum coherent (MQC) oscillations (Rabioscillations) between its two basis states, which are di ered by the direction of macroscopic current in the qubit loop.

Up till now the Rabioscillations in time dom $ain^{3,4}$ or as a function of the perturbation power^{5,6} have been detected indirectly through the statistics of switching events (e.g. escapes into continuum). In either case the probability P (t), or P (E), was to be obtained and analyzed to detect the oscillations.

M ore attractive in the long run is a direct detection of MQC oscillations through a weak continuous measurement of a classical variable, which would implicitly incorporate the statistics of quantum switching events, not destroying in the same time the quantum coherence of the qubit.^{7,8,9}

In this paper we describe the approach which allows a direct measuring of MQC oscillations of macroscopic current owing in a loop of a phase qubit. This qubit variety has the advantage of larger tolerance to external noise, especially to dangerous random background charge uctuations.¹⁰ To be speci c, we will use the example of three-junction small-inductance phase qubit (persistent current qubit²) where level anticrossing was already observed.¹¹

In our m ethod a resonant tank circuit with known inductance L_T , capacitance C_T and quality factor Q_T is coupled with a target Josephson circuit through the mutual inductance M (Fig.1). The m ethod was successfully applied to a three-junction qubit in classical regime,¹² when the hysteretic dependence of ground-state energy on the external magnetic ux was reconstructed in ac-

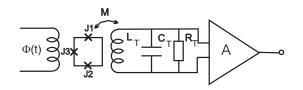


FIG.1: Phase qubit coupled to a tank circuit.

cordance to the predictions of R ef. 2.

The phase qubit is biased by external magnetic ux (t). A ssum ing sm all qubit self-inductance, we neglect the shielding current. Therefore the ux through the qubit loop is

$$(t) = _{x} + _{ac}(t);$$
 (1)

where $_{\rm x}$ is a time independent external ux, $_{\rm ac}$ (t) is a monochromatic high frequency ux from the external source.

If time-dependent external ux is applied to the qubit, the latter will be in a time-dependent superposition of states jDi and jLi. If the frequency of external ux is in resonance with the interlevel spacing of the qubit, the average current in the qubit loop will oscillate with the frequency which depends on the amplitude of external ux and can be made much smaller than the frequency of external signal. These smaller oscillations which are called R abioscillations can be detected with the aid of a high quality tank circuit coupled inductively to the qubit loop.

Below we nd the expression for the current in a qubit loop in presence of electrom agnetic resonant excitation for zero and non zero temperatures. We show that for typical parameters of three-junction phase qubit the current oscillations in a qubit loop give rise to the voltage oscillations across the tank with the amplitude which can be at the V level that makes a direct detection of Rabi oscillation possible.

II. QUANTUM DYNAM ICS OF 3JJ PHASE QUBIT

Quantum dynamics of three-junction phase qubit has been studied in detail in Ref. 2. The qubit consists of a loop with three Josephson junctions. The loop has very small inductance, typically in pH range. It insures effective decoupling of qubit from external environment. Two Josephson junctions have equal critical current I_C and capacitance C, while the critical current and capacitance of a third junction is a little bit smaller, $I_{\rm C}$, C where 0.5 < < 1. If the Josephson coupling energy $E_J = I_C \quad _0=2$, where $_0 = h=2e$ is a ux quantum , is much more than the C oulom b energy $E_{C} = e^{2}=2C$, then the phase of a Cooper pair wave function is well de ned. A swas shown in Refs. 1_{2} in the vicinity of $= 0^{-2}$ this system has two quantum stable states which macroscopically di er by the direction of the current circulating in a qubit loop. In the absence of high frequency excitation the quantum properties of the qubit are described by Ham iltonian (Eq. (12) in Ref. 2):

$$H_{0} = \frac{P_{r}^{2}}{2M_{r}} + \frac{P^{2}}{2M} + U(f; ;)$$
 (2)

where P, = ih@=@', P = ih@=@, M, = $(_{0}=2)^{2}2C$, M = $(_{0}=2)^{2}2C$ (1 + 2);

U (f;';) =
$$E_J f2 + 2\cos' \cos$$

 $\cos 2 f + \frac{1}{2} + 2$ (3)

Here $' = ('_1 + '_2)=2$, $= ('_1 - '_2)=2$), where $'_1$, $'_2$ are gauge-invariant phases of two Josephson junctions with equal critical currents. In contrast to Ref. 2, in (3) we de ne the ux bias f = = 0 $\frac{1}{2}$ as a sm all param eter m easuring the departure from degeneracy. At the degeneracy point f = 0 potential energy (3) shows two m in in a with equal energies $"_0$ at the points ' = 0, $_{\rm c}$; where $\cos_{\rm c} = 1=2$. The tunneling between = the minim a lifts the degeneracy leading to the energy levels $E = "_0$ where is a tunneling matrix element between two minima. However, at the degeneracy point the current in a qubit loop vanishes, so that it is necessary to move a little bit away from this point. In order to nd the levels in the close vicinity of degeneracy point we expand potential energy (3) near its m in in a taking account for linear term s in f and quadratic term s in quantum variables , .W ith the use of the technique described in Ref. 2 we nd the following expression for the energies of two levels:

$$E = \mathbf{"}_{0} \qquad \frac{q}{E_{J}^{2} f^{2} () + 2} \qquad (4)$$

where we take 0 set at the degeneracy point, i. e., f=0 corresponds to x = 0=2;

$$"_{0} = E_{J} \qquad 2 \quad \frac{1}{2} \quad + \quad \frac{s}{(E_{J} = E_{C})} \quad 1 + \stackrel{p}{2} \quad \frac{1}{2} \qquad (5)$$

$$() = - \frac{p_{4^{2}} + r_{4^{2}}}{p_{4^{2}} + p_{2^{2}} + 1} + \frac{p_{2^{2}} + 1}{p_{2^{2}} + 1}$$
(6)

Expression (4) di ers from corresponding equation in Ref.11 by a factor () which explicitly accounts for the dependence of the energies E on and $E_{\rm J}=E_{\rm C}$. The stationary state wave functions are eigenfunctions of H am iltonian H₀: H₀ = E . They can be written as the superpositions of the wave functions in the ux basis, L; R where L, R stand for the left, right well, respectively: = a $L + b_{\rm R}$.

$$a = p \frac{"_{+} E}{("_{+} E)^{2} + 2}; b = p \frac{"_{+} E}{("_{+} E)^{2} + 2};$$
(7)

where "₊ = h_L $\nexists_0 j_L i$; " = h_R $\nexists_0 j_R i$. For stationary states the current circulating in a qubit loop can be calculated either as the average of a current operator $\nexists_q = I_C \sin(\prime + \cdot)$ over stationary wave functions or as a derivative of the energy over the external ux:

$$I_{q} = h \quad j_{q}^{b} j \quad i = \frac{\partial E}{\partial} = I_{c} f \frac{2}{()} \frac{E_{J}}{h!_{0}} \quad (8)$$

where $h!_0 = E_+ E_-$.

Suppose we apply to the qubit the excitation on a frequency close to a gap frequency $! = h!_0$ 1 G H z. The corresponding perturbation term is then added to H am iltonian H₀: H_{int} = V(;) $\cos(!t)$ where V(;) in the vicinity of the left (right) m inimum is as follow s:

$$V_{L;R}(;') = E_{J} - f_{ac} \qquad p \frac{p}{4^{2}} \frac{2^{2}}{1} \qquad e^{2} \frac{p^{2}}{\frac{2^{2}}{4^{2}}} \frac{1}{1} \\ (c)^{2} \frac{p^{2}}{\frac{2^{2}}{4^{2}}} \frac{1}{1} \qquad (9)$$

$$_{\rm C} = _{\rm C} + 2 f \frac{1 2^2}{4^2 1}$$
 (10)

Throughout the paper we assume f 0, so that the bottom of the left well is higher than the bottom of the right well. Accordingly, in Eqs. (9) and (10) the upper sign refers to right m in im um , the lower sign refers to left m in im um . The quantity f_{ac} in Eq. (9) is the amplitude of excitation eld in ux units: $f_{ac} = ac = 0$. The high frequency excitation induces the transitions between two levels which result in a superposition state for the wave function of the system : $(t) = C_+ (t)_+ + C_- (t)$ The coe cients C (t) are obtained from the solution of time dependent Schrodinger equation with proper initial conditions for C (t). We assume that before the excitation the system was at the lower energy level: C (t = 0) = 1; C₊ (t = 0) = 0. The corresponding solution for C (t) in the rotating wave approximation is as

C (t) =
$$e^{\frac{i^{E}}{h}t}e^{\frac{i^{l}}{2}t}\cos t$$
 $i\frac{l}{2}\sin t$
C₊ (t) = $e^{\frac{i^{E}}{h}t}e^{\frac{i^{l}}{2}t}$ $i\frac{r}{2}\sin t$ (11)

where $_{r} = \frac{j_{h} + j_{v} j}{2h}i_{h}$, $= \frac{q}{(! + j_{0})^{2}} + \frac{2}{r}$. At resonance $(! = !_{0})$ we get $= _{r}$. Taking $_{L}$, $_{R}$ as ground state oscillatory wave functions in the left, right well, respectively, we calculate matrix element h_{+} j_{v} j_{-} i and obtain for R abi frequency:

$$r = \frac{E_{J}}{h} f_{ac} j () j_{h!_{0}}$$
(12)

As is seen from Eq. (12) by a proper choice of excitation power (f_{ac} in our case) the frequency r can be made much lower the gap frequency =h. Now we calculate the average current in a superposition state:

$$I_{q} = h(t)j I_{q}^{2}j(t)i$$

= jC_{+}(t)jh_{+}jI_{q}^{2}j_{+}i+jC_{-}(t)jh_{-}jI_{q}^{2}j_{-}i(13)

where we neglect high frequency $!_0$ term. A counting for the expression (8) for the current in stationary states we obtain at resonance the following expression for the average current owing in a qubit loop:

$$I_q = I_t f \frac{I_{a}^2()}{h!_0} \frac{E_J}{m!_0} \cos 2 rt$$
 (14)

At nite temperature the calculation of the current in a qubit loop in presence of high frequency excitation is based on the density matrix equation: ih_(t) = $[(H_0 + H_{int}(t)); (t)]$ with initial conditions at therm all equilibrium: __++ (0) = $\stackrel{eq}{_{++}}; (0) = \stackrel{eq}{_{+}}; (0) = \stackrel{eq}{_{++}}; (0) = \stackrel{eq}{_{++}}; (0) = \stackrel{eq}{_{++}}; (0) = \stackrel{eq}{_{++}}; (0) = \stackrel{eq}{_{-}}; (0) = \stackrel{eq$

In the rotating wave approximation the diagonal elements of density matrix at resonance $(! = !_0)$ are as follow s:

$$(t) = \frac{1}{2} + \frac{1}{2} \tanh \frac{h!_0}{2k_b T} \cos 2 rt; \qquad (15)$$

 $_{++}$ (t) = 1 (t).

Now we nd the average current at resonance for nonzero tem perature:

$$I_{q} = h_{+} j P_{q} j_{+} i_{++} (t) + h_{-} j P_{q} j_{-} i_{-} (t)$$
$$= E_{T} \frac{E_{J} f^{2} ()}{h!_{0}} tanh_{-} \frac{h!_{0}}{2k_{B} T} \cos 2_{r} t_{-} (16)$$

In order to estimate the Rabi frequency $_{\rm r}$ we take the following qubit parameters: $I_{\rm C}$ = 400 nA, =h = 0:3 GHz, = 0:8, L = 15 pH, E_J=E_C = 100. We take the amplitude of time-dependent ux which is coupled to qubit from high frequency source $f_{ac} = 1$ 10⁴. We set the ux o set from degeneracy point f = 3.5 10⁴, so that $h!_0 = 2^{2} 2$, $!_0=2 = 0.85$ GHz. For these values we obtain from Eq. (12) the Rabi frequency $_r=2 = 32$ MHz.

III. THE INTERACTION OF THE PHASE QUBIT W ITH A TANK CIRCUIT

The problem of a coupling a quantum object to the classical one, which is dissipative in its nature, has no unique theoretical solution. A rigorous approach is to start from exact H am iltonian which describes the qubit-tank circuit system :

$$H = H_0 + H_T + H_{0T} + H_{TB} + H_B$$
(17)

where H $_{\rm 0}$ is the qubit H am iltonian given in Eq. (2), H $_{\rm T}$ is the tank circuit H am iltonian

$$H_{T} = \frac{Q^{2}}{2C_{T}} + \frac{2}{2L_{T}}$$
(18)

where Q and are a quantum operators of the charge at the capacitor and of magnetic ux trapped by the inductor of a tank circuit, respectively. The operators obey commutator relation [;Q] = ih. The interaction H am iltonian between the qubit and the tank, H_{OT} is:

$$H_{0T} = \frac{M}{L} \hat{I}_{q}$$
(19)

where M is inductive coupling between qubit and the tank; H_B is the Ham iltonian of a therm al bath coupled to the tank via interaction H_{TB} = , where is the coupling constant between the tank and dissipative environment, is the dynamic variable of therm al bath H_B.

The equations of motion for tank circuit variables are as follows:

$$\frac{dQ}{dt} = \frac{M}{L_{T}} \frac{M}{L} \hat{I}_{q} +$$
(20)

$$\frac{d}{dt} = \frac{Q}{C_{T}}$$
(21)

From these two equations we get for the voltage operator $\hat{V} = Q = C_T$ across the tank:

$$\frac{d^2 \hat{V}}{dt^2} + !_T^2 \hat{V} = M !_T^2 \frac{d\hat{I}_q}{dt} + \frac{d}{dt}$$
(22)

The averaging of this equation over the bath leads to the dissipative equation for the average voltage, V, across the tank (see, for example, Ref. 14):

$$V + \frac{!_{T}}{Q_{T}}V + !_{T}^{2}V = M !_{T}^{2}\frac{dI_{q}}{dt}$$
 (23)

where $Q_{p} = !_T R_T C_T$ 1 is the tank quality factor, $!_T = 1 = L_T C_T$.

In the spirit of selective quantum evolution approach,⁸ we interpret Eq.23 as follows. Suppose the qubit is in a pure state, a f(i + b)(i): The tank voltage is measured (in quantum -mechanical sense) at certain times $t_k = t_k$

t;2 t; :::. Each time the qubit state is also measured, since there is correspondence between V (t_k) and qubit current, which thereby takes value either h0j \hat{I}_q (t_k) jDi or h1j \hat{I}_q (t_k) jLi, with appropriate probability. A veraging V (t_k) over intervals T two hich are still sm all com - pared to other characteristic times in the system, would yield Eq. 23.

The quantity to be detected is the oscillating voltage across the tank which at resonance is $V = V_a \cos 2$ rt, where the voltage am plitude, V_a is:

$$V_a = M Q I_C f \frac{2^{-2} ()}{h!_0} \frac{E_J}{h!_0} r$$
: (24)

It is the presence of these voltage oscillations in the detected signal which reveals the existence of R abi oscillations in the qubit.

The Eq. (23) is still quantum equation since the average voltage V is a quantum operator of the voltage across the tank averaged over the bath degrees of freedom. Therefore, our problem is reduced to the problem ofm easuring a weak external force (in our case, M dI_q=dt) by a dissipative oscillator. As is known (see, for example, Ref. 15) a classical descriptions of such oscillator requires that the quantum uctuations of the detector variable (i. e. V in our case) in the measurement bandwidth be smaller than the amplitude induced in the tank coil by external signal, M Q_T dI_q=dt. A coording to the uctuation-dissipation theorem the quantum uctuations of the voltage V are given by the spectral density:

$$S_V$$
 (!) = 2R eZ (!)h! coth $\frac{h!}{2k_B T}$ (25)

where $Z^{-1}(!) = (1=R_T + 1=i!L_T + i!C_T)$ is the impedance of a tank circuit.

Below we take the following parameters of the tank circuit: $L_T = 50 \text{ nH}$, Q = 1000, inductive coupling to qubit, $k^2 = M^2 = LL_T = 10^4$. We assume the tank is tuned to the frequency of oscillating current in the qubit, i. e., $!_T = 2 = 2 r = 2 = 64 \text{ MHz}$, hence, $C_T = 124 \text{ pF}$. We take the ux amplitude which is coupled to qubit from high frequency source $f_{ac} = 1 = 10^4$. We ext the ux o set from degeneracy point $f = 3.5 = 10^4$, so that $h!_0 = 2^5 2$, $!_0 = 2 = 0.85 \text{ GHz}$. For these values we obtain for the voltage amplitude at resonance $V_a = 0.7 \text{ V}$.

From Eq. (25) we estimate the voltage uctuations across the tank circuit coil at resonance (! = $!_T$):

$$V_{n} = \frac{S_{V}(!_{T})}{Z(!_{T})}!_{T}L_{T}Q_{T}\overset{P}{B}$$
(26)

where $B = !_T = 2 Q_T$ is the bandwidth of the tank circuit. We perform the calculations for T = 10 mK. For

the voltage uctuations we get $V_{\rm n}$ 10 nV. Thus, we see that the voltage uctuations across the tank coil is much smaller than the signal amplitude from the qubit. Therefore, we may treat the tank circuit as a classical object and the voltage V (t) as the classical variable coupled through Eq.23 to the qubit degree of freedom, where the current $I_{\rm q}$ in Eq.23 is calculated as the average of a current quantum operator over the qubit statistical operator.

IV. THE EFFECTS OF QUBIT RELAXATION AND DECOHERENCE

The estimations we made above are very promising, how ever, our derivation is made under a strong assum ption: we neglected the decoherence due to interaction of the qubit with external environm ent and with a measuring device. In fact, the possibility of detection of Rabi frequency depends crucially on relaxation, r, and decoherence, , rates, which lead to the decay of R abioscillations. The detection is in principle possible if period of oscillations is small compared to m in $[1 = , ; 1 = _r]$. The decoherence is caused primarily by coupling of a solid state based phase qubit to m icroscopic degrees of freedom in the solid. Fortunately this intrinsic decoherence has been found to be quite weak:¹⁶ the intrinsic decoherence times appeared to be on the order of 1 m s which is several orders of m agnitude m ore than period of current oscillations we estimated before: = r = 15.6 ns. However, the external sources of decoherence are more serious. In our method these are the microwave source which induces the Rabioscillations and the tank circuit which has to detect them . From this point two structures ofm icrow ave source has been analyzed: coaxial line that is inductively coupled to the qubit¹⁷ and on-chip oscillator based on overdam ped DC SQUD.¹⁸ The analysis has shown the relaxation and decoherence rates were on the order of 100 s at 30 m K for coaxial line, and 150 s and 300 s for relaxation and decoherence, respectively, for on-chip oscillator at 1 G H z. Here we estim ate decoherence times that are due to a tank circuit using the expressions for $\ _{\rm r}$ and $\ ,$ from 19

$$\frac{1}{T_{r}} = \frac{1}{2} - \frac{1}{h!_{0}} - \frac{2}{J} (!_{0}) \operatorname{coth} - \frac{h!_{0}}{2k_{B}T}$$
(27)

r

$$\frac{1}{T_{r}} = \frac{r}{2} + 2 \qquad \frac{E_{J}f}{h!_{0}} = \frac{k_{B}T}{h}$$
(28)

where dimensionless parameter rejects the 0 hm ic dissipation. It depends on the strength of noise coupling to the qubit. In our subsequent estimations we take = 5 10³ which is relevant for weak damping limit. Below we use the approach described in Ref. 20 in its simplified form $.^{17,18,21}$ W hile it is not mathematically rigorous, nevertheless it gives a correct order of magnitude of relaxation times. The quantity J (!₀) is the zero

tem perature spectral density of the uctuations of the gap energy of the qubit: $J(!) = < "(!) "(!) > =h^2$. The uctuations "are due to the ux noise f, which is supplied to the qubit by a tank circuit. From Eq.(5) we get " = $4E_{J}^{2} f = h!_{0}$ f, where f = M I= 0. The current noise I in a tank circuit inductance com es from two independent parts: Johnson-Nyquist voltage noise in a tank circuit resistance with a spectral density at T = 0: S_v (!) = 2h!ReZ (!), where Z ¹(!) = $(1=R_T + 1=i!L_T + i!C_T)$ is the impedance of a tank circuit, and from a current noise of pream pli er with a spectral density S_A . Therefore, we get for $J(!_0)$: $J_{\rm D}(!_0) = 4E_{\rm J}^2 {}^2 fM = h^2 !_0 {}_{\rm Q} {}^2 S_{\rm I}(!_0), \text{ where } S_{\rm I}(!) =$ S_V (!) R eZ (!) + S_A $\frac{1}{2}$ (!) $\frac{1}{2}$ = ! $^{2}L^{2}$ is the spectral density of a current noise in the tank circuit inductance. Since $!_0 >> !_T; S_I(!_0) = (2h!_0 = R_T + S_A) (!_T = !_0)^4$. For the estimation we take T = 10 mK, $R_T = 20 \text{ k}$, $S_A = 10^{26} A^2/Hz$, $!_T = 2 = 64 M Hz$, other parameters being the same as before. We nd that the contribution to the relaxation of a tank circuit noise and of pream pli er noise is approximately 0.1 s 1 and 22 s 1 , respectively. Therefore total relaxation is determined by pream pli er noise giving relaxation tim e $T_r = 45$ m s. The decoherence rate is dominated by a second term in (28), which is equal 5:4 10° s 1° giving decoherence time $T_{r} = 185 \text{ ns}$, which is approximately ten oscillation periods of circulating current. These estimations clearly

show the possibility of detection of Rabi frequency in M H z range with the aid of conventional rf circuitry.

Here we did not consider the e ect of a tank circuit back action on the qubit which can give additional contribution to the relaxation and decoherence rates. In order to reduce the back action e ect of a tank circuit and to further enhance the MQC signal it may be advantageous for detection of R abioscillations to use a two dimensional array of identical phase qubits coupled to a tank circuit. M odem technology allows several thousands of weakly coupled phase qubits to be obtained on a chip.¹⁷ P relim inary experiments showed that the behavior of m acroscopic current in such a system is completely analogous to that of longitudinal magnetization in NMR : the collective reversal of the persistent currents in the qubit loops when sweeping the ux bias within a degeneracy point has been observed.¹⁷

In conclusion, we have shown that Rabi oscillations (in M Hz range) of the current circulating in a qubit loop which are induced by high frequency external source (in G Hz range) can be detected in M Hz range as the voltage oscillations in the high quality tuned tank circuit inductively coupled to the qubit.

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